## HD155111F

## RF Single-chip Linear IC for PCN Cellular Systems

## HITACHI

## Description

The HD155111F was developed for PCN (DCS1800) cellular systems, and integrates most of the functions of a transceiver. The HD155111F incorporates the bias circuit for a RF LNA, a 1st mixer, 1st-IF amplifier, 2nd mixer, AGC amplifier and an IQ quadrature demodulator for the receiver, and an IQ quadrature modulator and offset PLL for the transmitter. Also, on chip are the dividers for the 1 st \& 2 nd local oscillator signals and $90^{\circ}$ phase splitter. Moreover the HD155111F includes control circuits to implement power saving modes. These functions can operate down to 2.7 V and are housed in a 48-pin LQFP SMD package.

Hence the HD155111F can form a small size transceiver handset for PCN by adding a PLL frequency synthesizer IC, a power amplifier and some external components. See page 7 "Configuration".

The HD155111F is fabricated using a $0.6 \mu \mathrm{~m}$ double-polysilicon Bi-CMOS process.

## Functions

## Receiver (RX)

- Low Noise Amplifier (LNA) bias circuit
- 1st mixer
- IF amplifier
- 2nd mixer
- Automatic gain control amplifier (AGC)
- IQ demodulator with $90^{\circ}$ phase splitter


## Transmitter (TX)

- IQ modulator with $90^{\circ}$ phase splitter
- Offset PLL
- Down converter
- Phase comparator
- TX VCO driver


## Others

- IF dividers
- Power saving circuit
- IFVCO


## Features

- Highly integrated RF processing for hand-portables
- Wide operating frequency

RX:
— RF: 1805 to 1880 MHz
— 1st IF: 130 to 300 MHz
— 2nd IF: 26 to 60 MHz
TX:

- RF: 1710 to 1785 MHz
- IF: 120 to 180 MHz
- Offset PLL architecture reduces TX spurious
- Low current consumption $(\mathrm{Vcc}=3 \mathrm{~V})$

RX mode: 42.5 mA Typ (including IFVCO current ( 2.5 mA Typ )) + LNA transistor current ( 5.6 mA Typ)
TX mode: 38.0 mA Typ (including IFVCO current ( 2.5 mA Typ))
Idle mode: $1 \mu \mathrm{~A}$ Typ

- Operating supply voltage:
— Phase comparator and TX VCO driver circuits: 2.7 to 5.25 V
— Other blocks: 2.7 to 3.6 V
- Operating temperature range: -20 to $+75^{\circ} \mathrm{C}$
- 48 pin SMD Low Profile Quad Flat Package (LQFP): FP-48


## Pin Arrangement

The HD155111F is housed in a 48-pin LQFP SMD package to which is suitable for applications where space is limited. "Pin Functions" shows the arrangement and roles assigned for each pin of the HD155111F.


## Pin Functions

| Pin <br> No. | Symbol | Input/ Output | Meaning of symbol | Function |
| :---: | :---: | :---: | :---: | :---: |
| 1 | POONRX1 | Input | POwer ON for RX1 | If ' H ', LNA and MIX1 are active. Other receiver blocks don't care. |
| 2 | POONRX2 | Input | POwer ON for RX2 | LNA and MIX1 don't care. <br> If 'H', Other receiver blocks are active. |
| 3 | RFOUT | Output | RF signal OUTput | Open collector type output of LNA. The collector of LNA transistor. |
| 4 | VCCLNA | Vcc | VCC of LNA block | Power supply of LNA |
| 5 | GNDLNA | Gnd | GND of LNA block | Ground of LNA |
| 6 | RFIN | Input | RF signal INput | Input of LNA. <br> The base of LNA transistor |
| 7 | POONTX | Input | POwer ON for TX | If ' $H$ ', the blocks for transmitter are active. The reciver blocks don't care. |
| 8 | VCCPLL | Vcc | VCC of OPLL block | Power supply for offset PLL except phase comparator |
| 9 | GNDPLL | Gnd | GND of OPLL block | Ground of offset PLL |
| 10 | VCOIN | Input | VCO signal INput | Input of Tx. VCO signal |
| 11 | vcccomp | Vcc | VCC of phase COMParator | Power supply for just phase comparator of offset PLL |
| 12 | PLLOUT | Output | OPLL OUTput | Current output to control and modulate Tx. VCO This pin should be connected external loop filter. |
| 13 | ICURAD | Input | I CURrent ADjust | This pin should be connected an external $R$ to determine charge pump current of phase comparator |
| 14 | QINB | Input | Q signal INput Bar | Q negative signal input of IQ quadrature modulator |
| 15 | QIN | Input | Q signal INput | Q positive signal input of IQ quadrature modulator |
| 16 | IINB | Input | $\underline{\underline{1} \text { signal INput Bar }}$ | I negative signal input of IQ quadrature modulator |
| 17 | IIN | Input | I signal INput | I positive signal input of IQ quadrature modulator |
| 18 | MODB | Output | MODulator output Bar | Negative output of IQ quadrature modulator |
| 19 | MOD | Output | MODulator output | Positive output of IQ quadrature modulator |
| 20 | VCCIQ | Vcc | VCC of IQ block | Power supply of IQ block |
| 21 | IFLO | Input/ Output | IF LOcal signal input/output | IF local signal input to be fed to divider |
| 22 | GNDIQ | Gnd | GND of IQ block | Ground of IQ block |
| 23 | IFVCOO | Output | IFVCO Output | Emitter of IFVCO transistor |
| 24 | IFVCOI | Input | IFVCO Input | Base of IFVCO transistor |

## Pin Function (cont)

| Pin <br> No. | Symbol | Input/ Output | Meaning of symbol | Function |
| :---: | :---: | :---: | :---: | :---: |
| 25 | QOUTB | Output | Q signal OUTput Bar | Q negative signal output of IQ quadrature demodulator |
| 26 | QOUT | Output | Q signal OUTput | Q positive signal output of IQ quadrature demodulator |
| 27 | IOUTB | Output | $\underline{1}$ signal OUTput Bar | I negative signal output of IQ quadrature demodulator |
| 28 | IOUT | Output | I signal OUTput | I positive signal output of IQ quadrature demodulator |
| 29 | VCONT | Input | Voltage of AGC CONTrol | The DC voltage input to control the power gain of AGC |
| 30 | GNDDIV | Gnd | GND of DIVider block | Ground of divider to make IF local signals |
| 31 | VCCDIV | Vcc | $\underline{\text { VCC of DIVider block }}$ | Power supply of divider to make IF local signals |
| 32 | AGCOUTB | Output | AGC OUTput Bar | AGC negative signal output to be fed to IQ quadrature demodulator |
| 33 | AGCOUT | Output | AGC OUTput | AGC positive signal output to be fed to IQ quadrature demodulator |
| 34 | VCCAGC | Vcc | VCC of AGC block | Power supply of AGC |
| 35 | GNDAGC | Gnd | GND of AGC block | Ground of AGC |
| 36 | MIX2OB | Output | MIX2 Output Bar | 2nd mixer (MIX2) negative signal output to be fed to AGC |
| 37 | MIX2O | Output | MIX2 Output | 2nd mixer (MIX2) positive signal output to be fed to AGC |
| 38 | IFINB | Input | 1stIF signal INput Bar | IFAMP negative signal input for 1st IF signal |
| 39 | IFIN | Input | 1stIF signal INput | IFAMP positive signal input for 1st IF signal |
| 40 | GNDIF | Gnd | GND of IFMIX2 block | Ground of IFAMP and 2nd mixer (MIX2) |
| 41 | VCCIF | Vcc | VCC of IFMIX2 block | Power supply of IFAMP and 2nd mixer (MIX2) |
| 42 | MIX1OUT | Output | MIX1 Output | 1st mixer (MIX1) positive signal output |
| 43 | MIX1OUTB | Output | MIX1 Output Bar | 1st mixer (MIX1) negative signal output |
| 44 | RFLOIN | Input | RF LOcal signal INput | RF 1st local signal input to be fed to 1 st mixer (MIX1) and the down converter of offset PLL |
| 45 | VCCMIX1 | Vcc | VCC of MIX1 block | Power supply of 1st mixer (MIX1) |
| 46 | GNDMIX1 | Gnd | GND of MIX1 block | Ground of 1st mixer (MIX1) |
| 47 | MIX1INB | Input | MIX1 Input Bar | 1st mixer (MIX1) negative signal input |
| 48 | MIX1IN | Input | MIX1 Input | 1st mixer (MIX1) positive signal input |

## Block Diagram



## Configuration

- Frequency Plan1

- Frequency Plan2



## A GSM Application Example



## Functional Operation

The HD155111F has been designed from system stand point and incorporated a large number of the circuit blocks necessary in the design of a digital cellular handset.

## Receiver Operation

The HD155111F incorporates a LNA bias circuit for an external RF transistor, whose NF and power gain can be better selected.

This circuit amplifies the RF signal after selection by the antenna filter before the signal enters the first mixer section. The RF signal is combined with a low side local oscillator (LO) signal to generate a wanted first IF signal in the 130 to 300 MHz range. The 1st mixer circuit uses a double-balanced Gilbert cell architecture, which has open collector differential outputs. If, at 225 MHz , a $800 \Omega \mathrm{LC}$ load is connected to the mixer's outputs then a SSB NF of 10 dB with a gain of 8.0 dB is realizable. The corresponding input compression point is -13 dBm , which allows the device to be used within a PCN system.

A filter is used after the 1st mixer to provide image rejection and the conditioned signal is then passed through an intermediate amplifier, before being down converted to a second IF in the range of 26 to 60 MHz .

The second mixer can generate a 45 MHz 2 nd IF, if a 270 MHz 2 nd LO signal is used. The 2 nd LO is obtained by dividing the IFLO signal by 2 . The 2 nd mixer also uses the Gilbert cell architecture, but with internal resistive differential outputs of $300 \Omega$. IF amplifier and second mixer has a SSB NF of 5.6 dB , a power gain of 12 dB and an input compression point of -25 dBm . In order to improve the blocking characteristics of the device an external LC resonator across the differential outputs of the second mixer is recommended.

The signal is then passed to the AGC circuit, which has a dynamic range of more than 80 dB ( -42 dB to +55 dB Typ) and is controlled by a DC voltage, which is generated by the microprocessor. This DC control range is from 0.15 V to 2.3 V . The AGC, which is designed for the PCN system, provides a linearity of $\pm 1.0 \mathrm{~dB}$ in any 20 dB window. The outputs of the AGC are $2 \mathrm{k} \Omega$ differential and are connected the external supply via inductors.

The signal is then down converted by a demodulator to I and Q. Internal divider circuits convert the IFLO signal to the same frequency as the 2nd IF before passing this local signal through a phase splitter / shifter in order to generate the in phase and quadrature IQ components. The phase accuracy of the IQ demodulator is $< \pm 1^{\circ}$ and the amplitude mismatch is $< \pm 0.5 \mathrm{~dB}$. In order to accommodate different baseband interfaces the HD155111F IQ differential outputs have a voltage swing of $2.4 \mathrm{Vp}-\mathrm{p}$ and a DC offset of $<60 \mathrm{mV}$ Max. Within each output stage a 2 nd order Butterworth filter ( $\mathrm{fc}=210 \mathrm{kHz}$ ), is used to improve the blocking performance of the device.

In order to allow flexibility in circuit implementation the HD155111F can configured to use either a singleended or balanced external circuitry and components.


Figure 1 LNA Bias Circuit

## Transmitter Operation

The transmitter chain converts differential IQ baseband signals to a suitable format for transmission by a power amplifier.

The common mode DC voltage range of the modulator inputs is 0.8 to 1.2 V and they have $2.4 \mathrm{Vp}-\mathrm{p}$ Max differential swing. The modulator circuit uses double-balanced mixers for the I and Q paths. The LO signals are generated by dividing the IFLO signal by 2 and then passing them through a phase splitter / shifter. The IF signals generated are then summed and produce a single modulated IF signal which is amplified and fed into the offset PLL block. Carrier suppression due to the mixer circuit is better than 31 dBc. However, if the common mode DC voltage of the I and Q inputs is adjusted, carrier suppression can be improved better than 40 dBc easily. In addition, upper side-band suppression is better than 35 dBc .

Within the offset PLL block there is a down converter, a phase comparator and a VCO driver. The down converter mixes the 1st LO signal and the TX VCO to create a reference LO signal for use in the offset PLL circuit. The phase comparator and the VCO driver generate an error current, which is proportional to the phase difference between the reference IF and the modulated IF signals. This current is used in a 2 nd order loop filter to generate a voltage, which in turn modulates the TX VCO. In order to optimize the PLL loop gain, the error current value can be modified by changing the value of an external resistor - ICURAD. In order to accommodate a range of TX VCO, the offset PLL circuit has been designed to operate with a supply voltage of up to 5.25 V .

## Operating Modes

The HD155111F has the necessary control circuitry to implement the necessary states within the PCN system. Also provided is a power save mode which reduces the current consumption of the device by powering down unnecessary function blocks. Three pins are assigned for mode control, POONRX1, POONRX2 and POONTX. Table 1 shows the relationship between the pins and the required operating mode. Control of these pins are by the system controller.

As per PCN requirements the TX and RX sections are not on at the same time. For the receiver there is a calibration mode for which the LNA bias circuit and 1st mixer are switched off. During this period the gain of the AGC can be adjusted. Also the DC offsets of the IQ demodulator are measured and subsequently canceled.

In order to change between the RX and TX modes a state called "warm-up" is used to ensure that the LO

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Power saving is implemented through use of the idle mode. All function blocks of the HD155111F are switched off until such time as the system controller commends the device to power up again.

Table 1 Operating Modes with Power Saving

|  |  | Receive (Rx) | Calibrate (Cal) | Warm-up (Lo-ON) | Transmit (Tx) | Idle (PS) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Mode <br> switch | POONRX1 (pin 1) | H | L | L | L | H |
|  | POONRX2 (pin 2) | H | H | L | L | L |
|  | POONTX (pin 7) | L | L | L | H | Don't care |
| HD155111F circuit status | LNA bias | ON | OFF | OFF | OFF | OFF |
|  | 1st mixer | ON | OFF | OFF | OFF | OFF |
|  | IF AMP | ON | ON | OFF | OFF | OFF |
|  | 2nd mixer | ON | ON | OFF | OFF | OFF |
|  | AGC | ON | ON | OFF | OFF | OFF |
|  | IO demodulator | ON | ON | OFF | OFF | OFF |
|  | Divider (Rx.) | ON | ON | OFF | OFF | OFF |
|  | Divider (Tx.) | OFF | OFF | OFF | ON | OFF |
|  | IO modulator | OFF | OFF | OFF | ON | OFF |
|  | Offset PLL | OFF | OFF | OFF | ON | OFF |
|  | RF 1st local buffer | ON | ON | ON | ON | OFF |
|  | IF local buffer | ON | ON | ON | ON | OFF |
|  | IFVCO | ON | ON | ON | ON | OFF |
|  | Total current | 42.5 mA Typ | 32 mA Typ | 10.5 mA Typ | 38 mA Typ | $1 \mu \mathrm{~A}$ Typ |



## IFVCO Operation

The HD155111F incorporates an IFVCO circuit. The IFVCO circuit consists of an IFVCO transistor and a bias circuit for it, whose current are 2.0 mA and 0.5 mA respectively. If an internal IFVCO is used, treat pin 23 (IFVCOO), pin 24 (IFVCOI) and pin 21 (IFLO) as shown figure 3-(a).

Using an external IFVCO, pin 23 (IFVCOO) and pin 24 (IFVCOI) cannot be connected any pattern and component, and any component to feed direct current must be also removed from pin 21 (IFLO).

If pin 23 (IFVCOO), pin 24 (IFVCOI) and pin 21 (IFLO) are treated as shown figure 3-(b), current consumption will decrease 2.0 mA .

Moreover, there is the other external IFVCO solution using only an IFVCO bias circuit as shown figure 3(c). The IFVCO bias circuit has an internal power save function. Therefore, if figure 3-(c) is adopted, an internal power save function can be used as well as figure 3-(a).


Figure 3 IFVCO Circuits

## Absolute Maximum Ratings

Any stresses in excess of the absolute maximum ratings can cause permanent damage to the HD155101BF.

| Item | Symbol | Rating | Unit |
| :--- | :--- | :--- | :--- |
| Power supply voltage (VCC) | VCC | -0.3 to +4.0 | V |
| Power supply voltage (VCCCOMP) | VCCCOMP | -0.3 to +5.5 | V |
| Pin voltage | $\mathrm{V}_{\mathrm{T}}$ | -0.3 to VCC $+0.3(6.0 \mathrm{Max})$ | V |
| Maximum power dissipation | $\mathrm{P}_{\mathrm{T}}$ | 400 | mW |
| Operating temperature | Topr | -20 to +75 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | Tstg | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

## Specifications

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions | Applicable pins | Note |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Power supply voltage (1) | $\mathrm{V}_{\mathrm{CC}}$ | 2.7 | 3.0 | 3.6 | V |  | $\begin{aligned} & 4,8,20,31, \\ & 34,41,45 \end{aligned}$ |  |
| Power supply voltage (2) | $\mathrm{V}_{\text {СссомP }}$ | 2.7 | 3.0 | 5.25 | V |  | 11 |  |
| Power supply current (Rx.) | $\mathrm{I}_{\mathrm{CC}(\mathrm{Rx} .)}$ | - | 42.5 | 60.0 | mA | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CccomP}}=3.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4,8,20,31 \\ & 34,41,45,11 \end{aligned}$ |  |
| Power supply current (Tx.) | $\mathrm{I}_{\mathrm{CC}(\mathrm{T} .)}$ | - | 38.0 | 55.0 | mA | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CCCOMP}}=3.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4,8,20,31 \\ & 34,41,45,11 \end{aligned}$ |  |
| Power supply current (Lo-ON) | $\mathrm{I}_{\text {CC(Lo-ON })}$ | - | 10.5 | 15.0 | mA | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CCCOMP}}=3.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4,8,20,31 \\ & 34,41,45,11 \end{aligned}$ |  |
| Power saving mode supply current | $\mathrm{I}_{\mathrm{CC}(\mathrm{PS})}$ | - | 1.0 | 10.0 | $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CCCOMP}}=3.0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 4,8,20,31 \\ & 34,41,45,11 \end{aligned}$ |  |
| Power up time (Rx.) | $t u_{(\text {Rx. })}$ | - | 1.5 | (5.0) | $\mu \mathrm{sec}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CCCOMP}}=3.0 \mathrm{~V} \end{aligned}$ |  | from PS <br> mode |
| Power up time (Tx.) | $\operatorname{tup}_{(T \mathrm{Tx} .)}$ | - | 0.2 | (0.5) | $\mu \mathrm{sec}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CCCOMP}}=3.0 \mathrm{~V} \end{aligned}$ |  | from PS <br> mode |
| Power on control voltage range (Rx1, Rx2, Tx) | Vthon ${ }_{\text {RX1 }}$ <br> Vthon $\mathrm{RX}_{\mathrm{R} 2}$ <br> Vthon ${ }_{\text {TX }}$ | 2.3 | - | - | V | $\mathrm{V}_{\mathrm{cc}}=3.0 \mathrm{~V}$ | $\begin{aligned} & 1 \\ & 2 \\ & 7 \end{aligned}$ |  |
| Power off control voltage range (RX1, Rx2, Tx) | Vthoff ${ }_{\text {RX1 }}$ <br> Vthoff ${ }_{\text {RX2 }}$ <br> Vthoff ${ }_{\text {TX }}$ | - | - | 0.8 | V | $\mathrm{V}_{\mathrm{cc}}=3.0 \mathrm{~V}$ | $\begin{aligned} & 1 \\ & 2 \\ & 7 \end{aligned}$ |  |
| I/Q common-mode output voltage | $\begin{aligned} & \mathrm{V}_{\text {IOcom }} / \\ & \mathrm{V}_{\text {QOcom }} \\ & \hline \end{aligned}$ | 1.1 | 1.3 | 1.5 | V | $\mathrm{V}_{\mathrm{cc}}=3.0 \mathrm{~V}$ | $\begin{aligned} & 25,26 \\ & 27,28 \end{aligned}$ |  |
| I/Q differential output swing | $\begin{aligned} & \mathrm{V}_{\text {IOsw }} / \\ & \mathrm{V}_{\text {QOsw }} \end{aligned}$ | 2.4 | 3.0 | - | Vp-p | $\begin{aligned} & V_{\text {CC }}=3.0 \mathrm{~V} \\ & V_{\text {IOUT }}-V_{\text {IOUTB }} \\ & V_{\text {QOUT }}-V_{\text {QOUTB }} \end{aligned}$ | $\begin{aligned} & 25,26 \\ & 27,28 \end{aligned}$ |  |
| I/Q output offset voltage | $V_{\text {IOoffsel }}$ <br> $\mathrm{V}_{\text {QOoffset }}$ | -60 | 0 | +60 | mV | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\text {IOUTDC }}-\mathrm{V}_{\text {IOUTBDC }} \\ & \mathrm{V}_{\text {QOUTDC }}-\mathrm{V}_{\text {QOUTBDC }} \end{aligned}$ | $\begin{aligned} & 25,26 \\ & 27,28 \end{aligned}$ |  |
| I/Q common-mode input voltage | $\begin{aligned} & \mathrm{V}_{\text {Ilcom }} / \\ & \mathrm{V}_{\text {Qlcom }} \end{aligned}$ | (0.8) | 1.0 | (1.2) | V | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | $\begin{aligned} & 14,15 \\ & 16,17 \end{aligned}$ |  |
| I/Q differential input swing | $\begin{aligned} & \mathrm{V}_{\text {Ilsw }} / \\ & \mathrm{V}_{\mathrm{Qlsw}} \end{aligned}$ | - | 2.0 | (2.4) | Vp-p | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{IN}}-\mathrm{V}_{\mathrm{IINB}} \\ & \mathrm{~V}_{\mathrm{QIN}}-\mathrm{V}_{\mathrm{QINB}} \end{aligned}$ | $\begin{aligned} & 14,15 \\ & 16,17 \end{aligned}$ |  |

Note: ( ) : These data are actual spread, not guaranteed.

## Block Specifications

| - Specifications of BRIGHT LNA <br> Item | Min | Typ | Max | Unit | Test Conditions |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Frequency (RF) | 1805 | 1840 | 1880 | MHz |  |
| Power gain | - | 13.0 | - | dB | $\mathrm{RF}=1840 \mathrm{MHz}, \mathrm{Pin}=-50 \mathrm{dBm}$ |
| Noise figure | - | 2.0 | - | dB | $\mathrm{RF}=1840 \mathrm{MHz}$ |
| i/p IP3 | - | -0.5 | - | dBm | $\mathrm{RF} 1=1840.8 \mathrm{MHz}, \mathrm{RF} 2=1841.6 \mathrm{MHz}$ |
| o/p IP3 | - | 12.5 | - | dBm | $\mathrm{RF} 1=1840.8 \mathrm{MHz}, \mathrm{RF} 2=1841.6 \mathrm{MHz}$ |
| i/p CP | - | -10.5 | - | dBm | $\mathrm{RF}=1840 \mathrm{MHz}$ |
| o/p CP | - | 1.4 | - | dBm | $\mathrm{RF}=1840 \mathrm{MHz}$ |
| Load Z | - | 50 | - | $\Omega$ | $50 \Omega$ Typ |
| i/p Z | - | 50 | - | $\Omega$ | $50 \Omega$ Typ |
| i/p VSWR | - | 1.5 | - |  | $\mathrm{RF}=1840 \mathrm{MHz}, 50 \Omega$ |
| o/p VSWR | - | 1.5 | - |  | $\mathrm{RF}=1840 \mathrm{MHz}, 50 \Omega$ |
| $\mathrm{I}_{\mathrm{cc}}$ @LNA Trs. | 4.7 | 5.6 | 6.8 | mA | Only Trs. current |

Note: These AC characteristics are shown for reference only and do not form part of the HD155111F component specification.

- Specifications of BRIGHT Mixer 1 (Output Load $=400 \Omega+400 \Omega$ balanced)

| Item | Min | Typ | Max | Unit | Test Conditions |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Frequency (RF) | 1805 | 1840 | 1880 | MHz |  |
| Frequency (LO) | 1505 | 1617 | 1750 | MHz |  |
| Frequency (IF) | $(130)$ | 225 | $(300)$ | MHz |  |
| RFLO input level | -10 | - | - | dBm |  |
| Conversion gain | 5.5 | 8.0 | 10.0 | dB | $\mathrm{RF}=1840 \mathrm{MHz} / \mathrm{Pin}=-50 \mathrm{dBm}$, <br> $\mathrm{LO}=1615 \mathrm{MHz} / \mathrm{Pin}=-10 \mathrm{dBm}, \mathrm{IF}=225 \mathrm{MHz}$ |
| Noise figure | $(7.0)$ | 9.0 | $(11.0)$ | dB | $\mathrm{RF}=1840 \mathrm{MHz}$, <br> $\mathrm{LO}=1615 \mathrm{MHz} / \mathrm{Pin}=-10 \mathrm{dBm}, \mathrm{IF}=225 \mathrm{MHz}$ |
| i/p IP3 | $(-8.0)$ | -5.0 | $(-2.5)$ | dBm | $\mathrm{RF} 1=1840.8 \mathrm{MHz}, \mathrm{RF} 2=1841.6 \mathrm{MHz}$, <br> $\mathrm{LO}=1615 \mathrm{MHz} / \mathrm{Pin}=-10 \mathrm{dBm}$ |
| o/p IP3 | $(-2.0)$ | 3.0 | $(7.0)$ | dBm | $\mathrm{RF} 1=1840.8 \mathrm{MHz}, \mathrm{RF} 2=1841.6 \mathrm{MHz}$, <br> $\mathrm{LO}=1615 \mathrm{MHz} / \mathrm{Pin}=-10 \mathrm{dBm}$ |
| i/p CP | -16.5 | -13.5 | $(-11.0)$ | dBm | $\mathrm{RF}=1840 \mathrm{MHz}$, <br> $\mathrm{LO}=1615 \mathrm{MHz} / \mathrm{Pin}=-10 \mathrm{dBm}, \mathrm{IF}=225 \mathrm{MHz}$ |
| o/p CP | $(-11.5)$ | -6.5 | $(-2.5)$ | dBm | $\mathrm{RF}=1840 \mathrm{MHz}$, <br> $\mathrm{LO}=1615 \mathrm{MHz} / \mathrm{Pin}=-10 \mathrm{dBm}, \mathrm{IF}=225 \mathrm{MHz}$ |
| RF i/p VSWR | - | 1.5 | $(2.0)$ |  | $\mathrm{RF}=1840 \mathrm{MHz}, 50 \Omega$ |
| LO i/p VSWR | - | 1.5 | $(2.0)$ |  | $\mathrm{RF}=1615 \mathrm{MHz}, 50 \Omega$ |

- Specifications of BRIGHT IFAmp + Mixer 2

| Item | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Input frequency (IF1) | (130) | 225 | (300) | MHz |  |
| Frequency (LO2) | (156) | 270 | (360) | MHz | $\mathrm{LO} 2=\mathrm{IFLO} / 2$ |
| Output frequency (IF2) | (26) | 45 | (60) | MHz |  |
| IFLO input level | -10 | - | - | dBm |  |
| Conversion gain | 9.0 | 12.0 | 14.5 | dB | $\begin{aligned} & \mathrm{IF} 1=225 \mathrm{MHz} / \text { Pin }=-40 \mathrm{dBm}, \\ & \text { IFLO }=540 \mathrm{MHz} / \text { Pin }=-10 \mathrm{dBm}, \mathrm{IF} 2=45 \mathrm{MHz} \end{aligned}$ |
| Noise figure | (4.5) | 5.6 | (7.0) | dB | $\begin{aligned} & \text { IF1 }=225 \mathrm{MHz}, \\ & \text { IFLO }=540 \mathrm{MHz} / \text { Pin }=-10 \mathrm{dBm}, \mathrm{IF} 2=45 \mathrm{MHz} \end{aligned}$ |
| i/p IP3 | - | -16.0 | - | dBm | $\begin{aligned} & \mathrm{IF} 11=225.8 \mathrm{MHz}, \mathrm{IF} 2=226.6 \mathrm{MHz}, \\ & \mathrm{IFLO}=540 \mathrm{MHz} / \mathrm{Pin}=-10 \mathrm{dBm} \end{aligned}$ |
| o/p IP3 | - | -4.0 | - | dBm | $\begin{aligned} & \text { IF11 }=225.8 \mathrm{MHz}, \text { IF2 }=226.6 \mathrm{MHz}, \\ & \text { IFLO }=540 \mathrm{MHz} / \text { Pin }=-10 \mathrm{dBm} \end{aligned}$ |
| i/p CP | -27.5 | -25 | (-23.0) | dBm | $\begin{aligned} & \mathrm{IF} 1=225 \mathrm{MHz} \\ & \mathrm{IFLO}=540 \mathrm{MHz} / \text { Pin }=-10 \mathrm{dBm}, \mathrm{IF} 2=45 \mathrm{MHz} \end{aligned}$ |
| o/p CP | (-18.0) | -14.0 | (-11.0) | dBm | $\begin{aligned} & \text { IF1 }=225 \mathrm{MHz}, \\ & \text { IFLO }=540 \mathrm{MHz} / \text { Pin }=-10 \mathrm{dBm}, \mathrm{IF} 2=45 \mathrm{MHz} \end{aligned}$ |
| Isolation | - | 60 | - | dB | Between mixer 1 outputs and IFAmp inputs |

Note: ( ) : These data are actual spread, not guaranteed.

- Specifications of BRIGHT AGC

| Item | Min | Typ | Max | Unit | Test Conditions |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Input frequency | $(26)$ | 45 | $(60)$ | MHz |  |
| Control voltage range | 0.15 | - | 2.3 | V |  |
| Gain range | 89 | 98 | 107 | dB | Gain 1 - Gain 3 |
| Gain linearity | $(-1.0)$ | - | $(1.0)$ | dB | in any 20dB window |
| Gain 1 | 45 | 55 | 65 | dB | Vcont $=2.3 \mathrm{~V}$ |
| Gain 2 | 13 | 23 | 33 | dB | Vcont $=1.5 \mathrm{~V}$ |
| Gain 3 | -55 | -40 | -35 | dB | Vcont $=0.15 \mathrm{~V}$ |
| i/p CP 1 | $(-64)$ | -59 | - | dBm | Gain $=50 \mathrm{~dB}$ |
| i/p CP 2 | $(-34)$ | -29 | - | dBm | Gain $=10 \mathrm{~dB}$ |
| i/p CP 3 | $(-22)$ | -17 | - | dBm | Gain $=-30 \mathrm{~dB}$ |
| N |  |  |  |  |  |

Note: ( ) : These data are actual spread, not guaranteed.

- Specifications of BRIGHT IQ Demodulator

| Item | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Power gain | -0.5 | 1.4 | 3.5 | dB | $\begin{aligned} & \text { IF2 }=45 \mathrm{MHz}, \text { Pin }=-25 \mathrm{dBm} \text {, Rout }=10 \mathrm{k} \Omega \text {, } \\ & \text { IFLO }=540 \mathrm{MHz}, \operatorname{Pin}=-10 \mathrm{dBm} \end{aligned}$ |
| i/p CP | (-17.5) | -16.0 | (-14.0) | dBm | $\begin{aligned} & \text { IF2 }=45 \mathrm{MHz} \text {, Baseband }=67.7 \mathrm{kHz} \text {, } \\ & \text { IFLO }=540 \mathrm{MHz}, \text { Pin }=-10 \mathrm{dBm} \end{aligned}$ |
| o/p CP | (-19.0) | -15.6 | (-12.0) | dBm | $\begin{aligned} & \text { IF2 }=45 \mathrm{MHz} \text {, Baseband }=67.7 \mathrm{kHz}, \\ & \text { IFLO }=540 \mathrm{MHz}, \text { Pin }=-10 \mathrm{dBm} \end{aligned}$ |
| IQ phase accuracy | -1.0 | 0 | 1.0 | deg. | Baseband $=67.7 \mathrm{kHz}$ |
| IQ amplitude mismatch | (-0.5) | 0.1 | (0.5) | dB | Baseband $=67.7 \mathrm{kHz}$ |
| Output DC offset voltage | -60 | 0 | 60 | mV | \|IOUT - IOUTB| and |QOUT - QOUTB| |
| IQ differential output swing | 2.4 | 3.0 | - | Vp-p | $\begin{aligned} & \text { Baseband }=67.7 \mathrm{kHz} \\ & \text { \|IOUT - IOUTB\| and \|QOUT - QOUTB\| } \end{aligned}$ |
| I/Q common mode output voltage | 1.1 | 1.3 | 1.5 | V | $\mathrm{V}_{\mathrm{cc}}=3.0 \mathrm{~V}$ |

Note: ( ) : These data are actual spread, not guaranteed.

- Specifications of BRIGHT IQ Modulator and Offset PLL

| Item | Min | Typ | Max | Unit | Test Conditions (Loop bandwidth $=1.4 \mathrm{MHz}$ ) |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Frequency (RF) | 1710 | 1747 | 1785 | MHz |  |
| Frequency (LO) | 1530 | 1612 | 1665 | MHz |  |
| Frequency (IF) | (120) | 135 | (180) | MHz |  |
| Power up time | - | 0.3 | (0.5) | $\mu \mathrm{sec}$ | from PS mode |
| Lock up time | - | 20 | (80) | $\mu \mathrm{sec}$ | from PS mode to 1880 MHz |
| IFLO input level | -10 | - | - | dBm |  |
| VCOIN input level | -10 | - | - | dBm |  |
| Carrier suppression ratio | 31 | 40 | - | dBc | All '1' GMSK (Baseband $=67.7 \mathrm{kHz}$ ) |
| Upper side-band suppression ratio | 35 | 45 | - | dBc | $\mathrm{I} / \mathrm{Q}$ differential input swing $=2.0 \mathrm{Vp}-\mathrm{p}$ $\mathrm{I} / \mathrm{Q}$ common mode input voltage $=1.0 \mathrm{~V}$ |
| Phase accuracy | - | 0.98 | (2.5) | deg. rms | 200kHz Bandwidth |
| (PN9, GMSK) | - | 2.74 | (6.0) | deg. peak | 200kHz Bandwidth |
| Modulation spurious | - | -36.0 | (-33.0) | dBc | 200 kHz offset / 30kHz Bandwidth |
| (PN9, GMSK) | - | -68.5 | (-63.0) | dBc | 400 kHz offset / 30kHz Bandwidth |
|  | - | -73.0 | (-63.0) | dBc | 600 kHz to 1.8 MHz offset / 30kHz Bandwidth |
|  | - | -73.5 | (-66.0) | dBc | 1.8 MHz to 3 MHz offset/ 100 kHz Bandwidth |
|  | - | -75.5 | (-68.0) | dBc | 3 MHz to 6MHz offset / 100kHz Bandwidth |
|  | - | -77.0 | (-74.0) | dBc | 6 MHz upwards offset / 100kHz Bandwidth |
| Tx noise in RX band | - | -156 | (-153) | $\mathrm{dBc} / \mathrm{Hz}$ | 1805 MHz to 20 MHz up from Tx band |
|  | - | -162 | (-153) | $\mathrm{dBc} / \mathrm{Hz}$ | 1850 MHz to 65 MHz up from Tx band |
| Isolation of the 1st local input to TXVCO input | (40) | 43 | - | dB |  |
| IQ differential input swing | - | 2.0 | (2.4) | Vp-p | \|IIN - IINB| and |QIN - QINB| |
| I/Q common mode input voltage | (0.8) | 1.0 | (1.2) | V |  |

Note: ( ) : These data are actual spread, not guaranteed.

## Test Circuit



## Measurement Results

LNA Measurement Results (for reference only)

|  |
| :---: |

Figure 4 Evaluation Circuit for LNA


Figure 5 Gain, NF, ICP vs. Frequency


Figure 6 Gain, Pout vs. Pin


Figure 7 Gain vs. Supply Voltage


Figure 8 NF vs. Supply Voltage


Figure 9 ICP vs. Supply Voltage


Figure 10 LNA Transistor Current vs. Supply Voltage

## 1st Mixer Measurement Results

Conditions:
Vcc $=3.0 \mathrm{~V}$
POONRX1 (pin 1) $=3.0 \mathrm{~V}$
POONRX2 (pin 2) $=3.0 \mathrm{~V}$
POONTX (pin 7 ) $=0 \mathrm{~V}$

Figure 11 Evaluation Circuit for 1st Mixer


Figure 12 Gain, NF, ICP vs. Frequency


Figure 13 Gain, Pout vs. Pin


Figure 14 CG, NF vs. Local Input Power


Figure 15 Output Frequency Characteristics


Figure 16 Gain vs. Supply Voltage


Figure 17 NF(SSB) vs. Supply Voltage


Figure 18 ICP vs. Supply Voltage

IF AMP + 2nd Mixer Measurement Results


Figure 19 Evaluation Circuit for IF AMP + 2nd Mixer


Figure 20 Input-Output Characteristics, 1dB-Compression Point


Figure 21 Intermodulation 3rd Characteristics


Figure 22 C.Gain vs. Local in Power


Figure 23 C.Gain, NF SSB vs. Supply Voltage


Figure 24 ICP vs. Temperature

## AGC Measurement Results



Figure 25 Evaluation Circuit for the AGC \& Power On Control Blocks


Figure 26 Power Gain vs. Vcont Voltage


Figure 27 Power Gain vs. Frequency


Figure 28 Noise Figure(NF) vs. Power Gain(Gp)


Figure 29 Input Compression Point(ICP) vs. Power Gain(Gp)


Figure 30 Power Gain(Gp) vs. Supply Voltage(Vcc)

## IQ Demodulator Measurement Results



Figure 31 Evaluation Circuit for the I\&Q Demodulator Block


Figure 32 Input-Output Characteristics


Figure 33 Input-Output Characteristics


Figure 34 Inter Modulation 3rd Characteristics

| Rejection | spec.(Min) | lout | Qout |
| :--- | :--- | :--- | :--- |
| $@ 200 \mathrm{k}$ | -0.3 dB | -2.6 dB | -2.4 dB |
| $@ 400 \mathrm{k}$ | -4.0 dB | -11.5 dB | -11.2 dB |
| $@ 600 \mathrm{k}$ | -9.4 dB | -21.3 dB | -21.1 dB |
| $@ 800 \mathrm{k}$ | -14.0 dB | -29.0 dB | -28.7 dB |
| $@ 1600 \mathrm{k}$ | -25.9 dB | -43.3 dB | -43.0 dB |
| $@ 3000 \mathrm{k}$ | -36.8 dB | -42.2 dB | -42.0 dB |
| $@ 20000 \mathrm{k}$ | -50.0 dB | -54.7 dB | -56.1 dB |




Figure 36 Demodulator Output Waveforms ( 67.7 kHz ) at Vcc $=\mathbf{3 . 0} \mathrm{V}, \mathbf{T a}=25^{\circ} \mathrm{C}$

## Transmitter Measurement Results



Figure 37 Evaluation Circuit for the Upconverter (I\&Q Modulator and Offset PLL Block)


Transmitter Measurement Results (1) $\left(\mathrm{R}_{\text {ICURAD }}=22 \mathrm{k} \Omega\right.$ and IFLO generated by signal generator)


Figure 39 Evaluation Circuit Using Signal Generator for the I\&Q Modulator and Offset PLL
Table 2 Measurement Results Using SG $\left(\mathrm{R}_{\text {ICURAD }}=22 \mathrm{k} \Omega\right.$, IFLO generated by signal generator $)$

| Item |  | Spec. | Measured1 | Measured2 | Measured3 | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Measured frequency |  |  | 1710 | 1747 | 1785 | MHz |
| 200 kHz offset |  | $\leq-33$ | -36.54 | -36.25 | -36.42 | dBc |
| 400 kHz offset |  | $\leq-63$ | -67.16 | -67.28 | -67.43 | dBc |
| 600 kHz to 1.8 MHz offset |  | $\leq-63$ | -71.44 | -71.48 | -71.67 | dBc |
| 1.8 MHz to 3 MHz offset |  | $\leq-66$ | -73.32 | -73.33 | -73.44 | dBc |
| 3 MHz to 6 MHz offset |  | $\leq-68$ | -75.32 | -75.09 | -75.20 | dBC |
| 6 MHz upwards offset |  | $\leq-74$ | -76.01 | -75.95 | -75.98 | dBC |
| Carrier suppression |  | $\geq 31$ | 45.13 | 45.13 | 45.13 | dBc |
| Side band suppression |  | $\geq 35$ | 41.89 | 41.93 | 41.93 | dBc |
| Phase accuracy | PN9 | $\leq 2.5$ | 0.95 | 0.96 | 0.96 | deg. rms |
|  | PN9 | $\leq 6.0$ | 2.49 | 2.42 | 2.39 | deg. peak |
|  | All ' 1 ' | $\leq 2.5$ | 0.81 | 0.80 | 0.80 | deg. rms |
|  | All ' 1 ' | $\leq 6.0$ | 1.97 | 1.94 | 1.95 | deg. peak |


a-1. Spectrum1(1710MHz,PN9)

b-1. Spectrum1 (1747MHz,PN9)

c-1. Spectrum1(1785MHz,PN9)

a-2. Spectrum2(1710MHz,PN9)

b-2. Spectrum2(1747MHz,PN9)

c-2. Spectrum2(1785MHz,PN9)

Figure 40 GMSK Modulated Transmitter Output Spectrum ( $1710 \mathrm{MHz}, 1747 \mathrm{MHz}, 1785 \mathrm{MHz}$ )


Figure 41 GMSK Modulated Transmitter Output Spectrum vs. Temperature

The Acquisition response of OPLL using $22 \mathrm{k} \Omega$ icurad is shown below. The control voltage of the VCO was observed by the digital storage oscilloscope.


Figure 42 Acquisition Time (Lock Up Time)

## Package Dimesions



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